

Preliminary Specification Revision 1.1 August 1997





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1 Definitions

1.1 Objective of the Specifications

This specification lists the parameters to be fulfilled by the HITAG 1 chip module HT1 MOA3 S30 for contactless smart cards or similar transponders (as e.g. discs).

1.2 Definition of the Chip Module

A chip module is an electronically packaged chip covered with a globe top cap. The HT1 MOA3 S30 is above all used as card module, i.e. for further lamination into contactless smart cards according to ISO 10536.1.

So the HITAG 1 chip module HT1 MOA3 S30 is best suited for customers that do not want to spend time with micro assembly and therefore start - e.g. ISO card production - with the HITAG 1 chip module.

1.3 Use of the Modules

The HITAG 1 modules are designed to be connected to a coil and then to be further processed by packaging into a transponder (e.g. lamination into an ISO smart card). Specific processing information for the coil-module connection and packaging is given in the specification.

For production of contactless chip cards it is recommended to prepunch card foils to create a recess for the chip module in the card body.

2 Specifications

2.1 Mechanical Properties

Width (Proposed Punching Outline)	7.55 mm	
Length (Proposed Punching Outline)	11.75 mm	see also drawing in chapter 3
Overall Thickness	0.45 mm ± 0.03 mm	
Film Thickness	0.16 mm ± 0.005 mm	
Bondpad Size for Transponder Coil / Module Interconnection	1.9 x 3.5 mm	Suitable for Welding/Soldering/ Conductive Gluing

2.2 Materials

Таре	110 µm	Glass epoxy
Copper Plating	35 µm	ED copper
Bond Plating	Ni / Au	Suitable for AI and Au wire bonding
Backside Plating	Ni / Au	
Glob Top	Filled Epoxy	Thermal curing

2.3 Temperature Range

Operating	-25°C to +85°C	For packed transponder, depending on type of package
Processing	150°C for 30 minutes	at a standard lamination pressure for contactless smart card plastic materials (e.g. PVC, PET,)
Welding Parameters	max. 25 ms @ 500 °C	on bond pads
Soldering Parameters	max. 3 s @ 390 °C	on bond pads

2.4 Storage Conditions

Temperature	15 - 30 °C	
Relative Humidity	40 - 70 %	
Duration	1 year	

2.5 Delivery Conditions

Delivery Identification	Date of ready for shipment, reel numbers, total quantity of good modules with the detail of good modules per reel, order number, product type, no supplier identification on reels, bags and boxes.			
Types of Delivery	Chip modules on reel	approx. 15.000 to 20.000 pcs. per reel, tape width super 35 mm, pitch 9,5 mm, 2 rows		
	single chip modules (bulk goods)	500 pcs . per bag		
Packing and Transport	According to documentation "Packing Method Modules (reel)"	Order-No. 3322 845 04881		
	"Packing Method Modules (singulated)"			
Bad Module Marking	All bad modules (mechanical and electrical faults) must be punched by reject hole for customer	see drawings chapter 3		
	Bad positions (reel): <20%			
Splicing Specifications	Tape material: adhes. tape 15,5 +/- 0,7 mm, thermal resistance at <190°C by < 100 cN tractive power and < 30 sec. duration.	see drawings chapter 3		
Labeling	Identification label on the reel and on carton bag: - Product type			
	 Number of the reel Total number of positions Number of good positions Date of sealing (to be checked) Two batches per reel only Batchnumber indication (only coded, to be checked) 			

2.6 Electrical Specifications

	Symbol	min	typ	max	Comment / Conditions
Absolute Maximum Ratings					
Junction Temperature	TJ	-55°C		140°C	
Input Peak Current	I _{INpeak}			30 mA	
Latch up Current		100 mA			MIL-STD 883D, Method 3023
ESD		2 kV			MIL-STD 883D, Method 3015.7, Human Body
Operating Range					
Temperature	T _A	-40°C		85°C	$\label{eq:RThJunctionAmbient} \begin{array}{l} R_{ThJunctionAmbient} \leq 30 \ \text{K/W} @ \\ I_{INpeak} = 30 \ \text{mA} \end{array}$
Input Threshold Voltage ^{1) 3)}	V _{IN,TH}		3,1 V _p	4,2 V _p	start modulation after SETCC
Input Read Voltage ^{1) 3)}	V _{IN,RD}		3,5 V _p	4,5 V _p	read E ² PROM
Input Write Voltage ^{1) 3)}	V _{IN,WR}		3,7 Vp	4,7 V _p	write E ² PROM
Demodulator					
Range ³⁾	V _{DEM_R}	2,0 V _p		4,0 V _p	$V_{INHigh} - V_{INLow} @ V_{INHigh} = 5,0 V_p$ T ₀ =8 µs, T _{MOD} =6 [*] T ₀ ²⁾
Modulator					
R_MOD linear ³⁾	R _{MODL}			4,5 kΩ	$V_{INLow} \le 2,0 V_p$
R_MOD nonlinear ³⁾	R _{MODNL}	1		3,6 kΩ	$V_{INLow} \ge 2,0 V_p$
Resonance Capacitor ³⁾					
	C _{ResInit}	189 pF	210 pF	231 pF	$V_{IN} = 4,0 V_p$

EEPROM				
Write Current ⁴⁾	Iw		25 µA	V _{DD} = 2,8 V
Read Current ⁴⁾	I _R		9 µA	V _{DD} = 2,8 V
Data Retention	Years	10		@ 55°C
Write Endurance	Cycles	100.000		

1)

 $|V_{IN}| = |V_{IN1} - V_{IN2}|$... voltage between connection pads

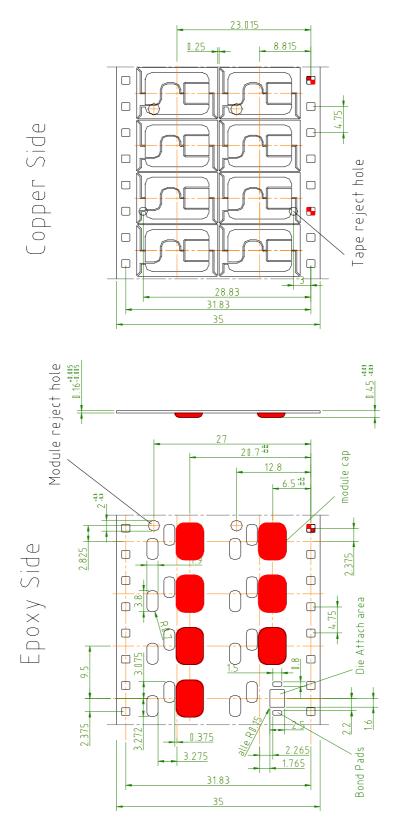
²⁾ V_{INHigh} input voltage before modulation
 V_{INLow} input voltage during modulation
 T_{MOD} duration of the modulation

³⁾ @ $R_i = 10 \text{ k}\Omega$ resistance of measurement equipment

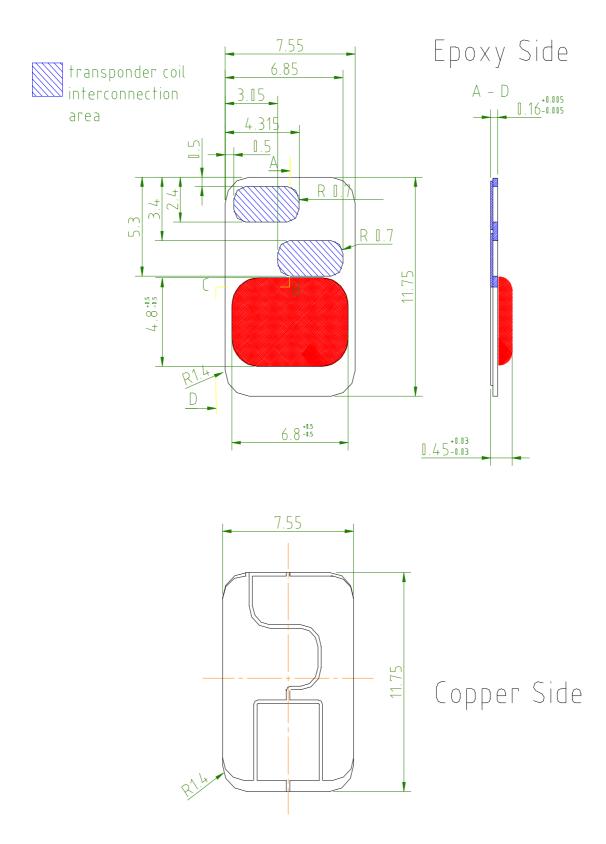
⁴⁾ tested on silicon level

3 Drawing of the Chip Module HT1 MOA3 S30

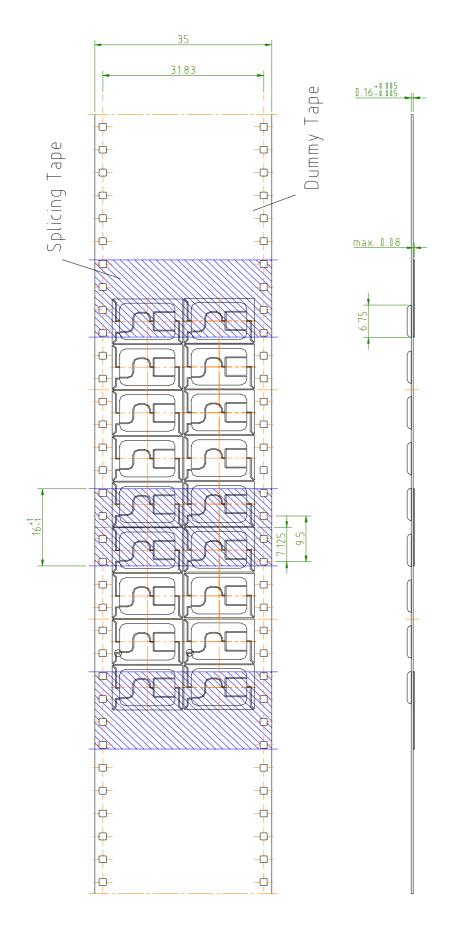
3.1 Drawing of the Reel



3.2 Module outline suggestion



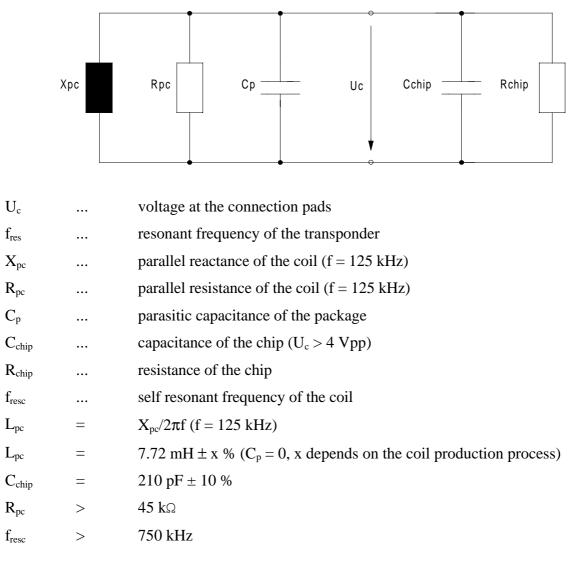
3.3 Splicing Specification



4 Coil Specifications

The HITAG 1 chip module has to be connected to a coil whose parameters are briefly described in the following.

Equivalent circuit of the transponder



Note: The parasitic capacitance of the package (C_p) must be considered.

$$f_{\rm res} = \frac{1}{2\pi \sqrt{(C_{\rm chip} + C_{\rm p}).L_{\rm pc}}} = 125 \text{ kHz} \implies L_{\rm pc} = \frac{1}{(2\pi f_{\rm res})^2 (C_{\rm chip} + C_{\rm p})}$$

Typical values for C_p hot laminated cards: $C_p = 1.5 \text{ pF}$ moulded tags: $C_p = 6.0 \text{ pF}$

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$$N = \sqrt[1,85]{\frac{L}{2 U \ln \left(\frac{u}{d}\right)}}$$

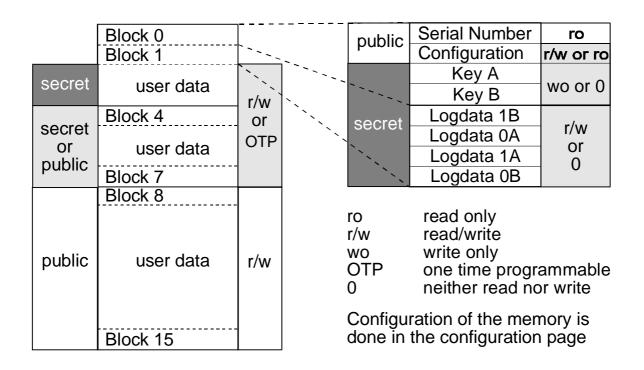
- N ... Number of windings
- L ... Inductance [nH]
- U ... average coil circumference [cm]
- d ... copper diameter [mm]
- u ... average coil circumference [mm]

For fine tuning a measurement of the inductance and an according adjustment of the number of windings is necessary. This process always needs some iterations.

5 Functional Description of HITAG 1

5.1 Memory Organization

The 2 kBit EEPROM memory on the transponder is divided into 16 blocks. Every block consists of 4 pages. A page is the smallest access unit. Every page consists of 4 bytes (at 8 bits). Block access is only available for Blocks 2-15, page access is available for Pages 0-63.



Areas (or settings) with light dark background may be configured by the OEM client using the Configuration Page (Page 1).

Memory locations marked with "secret" can only be accessed after a mutual authentication. An enciphered data communication is used in that area.

Memory locations marked with "public" can be accessed without mutual authentication, no encryption is used.

Block 0 includes the unique serial number (programmed during the production process), the Configuration Page (configuration of the memory area) and the keys, Block 1 includes the logdata.

Blocks 4 to 7 can be used either as secret or public areas (configurable), and Blocks 2 to 7 either as read / write or read only areas (configurable). You can also modify keys and logdata and prevent them from being accessed.

Finally the Configuration Page itself can be set to read only.

It is extremely important to be particularly careful when using the Configuration Page (it only can be set to read only once!), keys and logdata as you can lose access to the secret area on the transponder in case of a mistake.

ATTENTION:

Changing of the Configuration Page (Page 1), Keys and Logdata must be done in secure environment. The transponder must not be moved out of the communication field of the antenna during programming! We recommend to put the transponder close to the antenna (zero-distance) and not to remove it during programming.

5.2 Anticollision

Anticollision Mode in long range applications including HITAG 1 transponders permits you to process several transponders simultaneously. Theoretically up to 2^{32} transponders can be processed simultaneously. In practice this number is limited, because of the mutual influence of the transponders - they detune each other, if there are too many too close to each other.

The currently used read/write device must also support full anticollision feature (e.g. HTRM800). For read/write devices without that feature only one transponder is handled even if there are several transponders within the communication field of the antenna. In this case either no communication takes place or the "stronger" or closer transponder takes over.

By muting a selected transponder (HALT Mode) another transponder that is to be found in the communication field of the antenna can be recognized.

5.3 Operation Modes and Configuration

5.3.1 Modes of Operation

The HITAG 1 can be operated in two modes (Standard Protocol Mode, Advanced Protocol Mode) that **cannot** be configured using the Configuration Page, but via special host commands.

Advanced Protocol Mode is not available for HITAG 1 transponders based on ASIC HT1 ICS30 01x (only available for HITAG 1 transponders based on ASIC HT1 ICS30 02x) and uses, above all, an additional Cyclic Redundancy Check (CRC) for read operations.

5.3.2 Configuration

The Configuration Page consists of 4 Configuration Bytes, the first two bytes are used for configuration, the other two bytes can be used freely.

The bitmaps in Configuration Bytes 0 and 1 determine the configuration of the memory, i.e. they define which area is secret or public, read/write, read only, write only or neither read nor write.

You can allocate and write the Configuration Page until it is locked (Bit 4 of Configuration Byte 1 is set to '0').

After that these bytes are read only bytes and the configuration of the transponder memory cannot be changed any more.

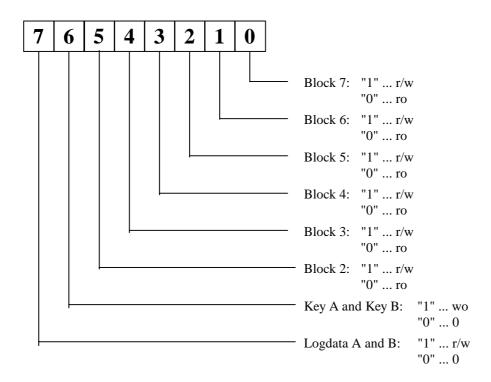
ATTENTION: Once set to read only the Configuration Page cannot be changed back to read/write again (transponder is hardware protected)!

Configuration Bytes 2 and 3: These two bytes, too, are set to read only by the OEM Lock Bit (Configuration Byte 1 / Bit 4 = "0"). Considering that fact you can use these two bytes freely. They will not affect memory configuration.

Explanations of abbreviations used:

r/w	read and write
ro	read only
wo	write only
0	neither read nor write

Configuration Byte 0:



Configuration Byte 0 / Bit 7:

Bit 7 = '1': Logdata can be read and written to. Bit 7 = '0': Logdata cannot be accessed.

This bit can be set or reset until Bit 4 of Configuraion Byte 1 is set to '0'.

For further information on Logdata and Keys see chapter "Definition of Keys and Logdata".

Configuration Byte 0 / Bit 6:

Bit 6 = '1': Keys can only be written to. Bit 6 = '0': Keys cannot be accessed.

This bit can be set or reset until Bit 4 of Configuration Byte 1 is set to '0'.

For further information on Logdata and Keys see chapter "Definition of Keys and Logdata".

Configuration Byte 0 / Bits 0 ... 5:

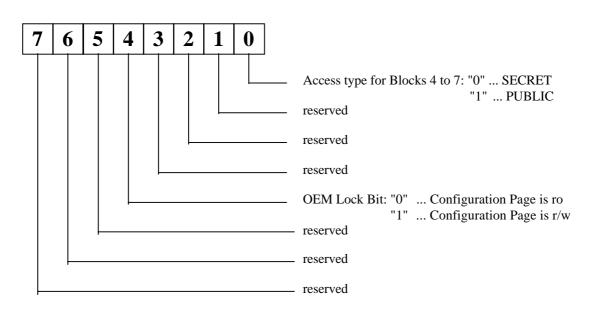
If one of these Configuration Bits is '1', the corresponding block of the transponder can be read and written.

If the bit is set to '0', the corresponding block can only be read.

Within one block the configuration is always identical, that means either all 4 pages are read/write or all of them are read only.

These bits can be set or reset until Bit 4 of Configuration Byte 1 is set to '0'.

Configuration Byte 1:



Configuration Byte 1 / Bits 5 ... 7:

These three bits are reserved.

ATTENTION: When writing a new value to Configuration Byte 1, bit positions marked as "reserved" must not be altered. To meet that condition read the current Configuration Byte 1 value and mask in your new values for bit positions you are allowed to change.

Configuration Byte 1 / Bit 4:

Bit 4 = '1': Configuration Page can be read and written to. Bit 4 = '0': Configuration Page can only be read. This process is irreversible !

ATTENTION: Do not set Bit 4 of Configuration Byte 1 to '0' before having written the final data into the Configuration Page of the transponder.

Configuration Byte 1 / Bits 1 ... 3:

These three bits are reserved.

ATTENTION: When writing a new value to Configuration Byte 1, bit positions marked as "reserved" must not be altered. To meet that condition read the current Configuration Byte 1 value and mask in your new values for bit positions you are allowed to change.

Configuration Byte 1 / Bit 0:

Bit 0 = '0': Access type for Blocks 4 to 7 is SECRET. Bit 0 = '1': Access type for Blocks 4 to 7 is PUBLIC.

This bit can be set or reset until Bit 4 of Configuration Byte 1 is set to '0'.

5.4 Configuration of Delivered HITAG 1 Transponders

HITAG 1 transponders are delivered with the following configuration by Philips Semiconductors:

Unique Serial Number: Serial Number:	Read Only	-	fixed
Configuration Byte 0:			
Logdata:	'1' = r/w	-	can be changed
Key A, Key B:	'1' = wo	-	can be changed
Blocks 2 - 7:	1' = r/w	-	can be changed
Configuration Byte 1:			
OEM Lock Bit:	'1' = Configuration Page is r/w	-	can be changed
Blocks 4 - 7:	'1' = public	-	can be changed

Value for Transport Keys, Transport Logdata:

0x00000000

RECOMMENDATION:

Before delivering transponders to end users, the Configuration Page should be set to read only (Configuration Byte 1/Bit 4 = 0).

5.5 Definition of Keys and Logdata

In order to be able to read data from the secret area of a transponder, you have to carry out a procedure called authentication. To do this you need special data (keys).

After transmitting the according command the authentication is automatically carried out by the read/write device.

Keys are cryptographic codes, which determine data encryption during data transfer between read/write device and transponder.

Two keys (Key A and Key B) which you can use independently of each other, have been installed for security and flexibility reasons. The identity of either Key A or Key B on the read/write device and on the transponder is sufficient.

Logdata represent "passwords" needed to gain access to secret areas on the transponder. A pair of logdata is included with every cryptographic key (Key A and Key B). This logdata pair has to be identical both on the transponder and the read/write device.

ad Key A:	Logdata 0 A	"Password" which the transponder sends to the read/write device and which is verified by the latter.
	Logdata 1 A	"Password" which the read/write device sends to the transponder and which is checked for identity by the latter.
ad Key B:	Logdata 0 B and Logdata 1 B	analogous to Key A

on the read/write		on the transponder	
device			
KEY A	\Leftrightarrow	KEY A	7
LOGDATA 0A	₿	LOGDATA 0A	} Set A
LOGDATA 1A	\Leftrightarrow	LOGDATA 1A]
KEY B	\Leftrightarrow	KEY B	1
LOGDATA 0B	₿	LOGDATA 0B	} Set B
LOGDATA 1B	\Leftrightarrow	LOGDATA 1B]

It is important that the following values are in accordance with each other, i.e. the respective data on the read/write device and on the transponder have to be identical pairs:

The keys and logdata are predefined by Philips Semiconductors by means of defined Transport Keys (both keys show the same bit map) and Transport Logdata (all logdata show the same bit map), see also chapter "Configuration of Delivered HITAG 1 Transponders". They can be written to, which means that they can be changed.

ATTENTION: Keys and Logdata only can be changed if their current values are known!

6 Quality Inspection

Quality inspection is performed with statistical quality control according to ISO 2859 part 1, with AQL1.0.

Optical Properties	scratches, encapsulation failures, gold discolouration, delamination	according to the reference sample catalogue
Geometrical Properies	width	measured with gauge
	length	measured with gauge
	overall thickness	measured with micrometer at the center of the glob top
Electrical Properties	operation	basic read/write operations
Shipment Quantity		
Packing and Labeling		

7 Characterisation and Test of the Final Transponder

7.1 Characterisation of the Transponder

The parameters recommended to be characterised for the transponder are:

Parameter		Comment	
Resonant frequency	f _{res}	Transponder does not modulate Resonant frequency @ $T_{amb} = 22^{\circ}C$, @ B_{TH}	
Threshold value	Втн	Start of modulation	
Threshold value for READ	B _{RD}	Command READ_PAGE OK	
Threshold value for WRITE	B _{WR}	Command WRITE_PAGE OK	

For the measurement of these parameters we recommend to use the test equipment available from **SCEMTEC, Marienheide-Rodt, Germany (Transponder Measurement System STM-1).** This device also supports functional testing (besides parameter testing). Therefore it can also be used as production test equipment for the final transponder test. For further information please contact Scemtec GmbH.

7.2 Final Test of the Transponder

In addition to the equipment described in the previous chapter Philips Semiconductors offers a device for a final functional test of transponders, the HITAGTM Test System HT OT490. Parameter tests are not supported by this device.

Basic flow for production and test:

- 1. Assembly of transponders
- 2. Functional test and final test of the EEPROM

Since the Keys and Logdata are changed during final test the Configuration and personalization must take place after the final test. The final test is disabled (not reversible) by setting the Tag-test mode bit to 0.

For the final test of transponders we recommend to use the HITAGTM Test System HT OT490 of Philips Semiconductors or the Transponder Measurement System STM-1 of Scemtec.

8 Ordering Information

Type Name	Description	Ordering Number
HT1 MOA3 S30/E/3	HITAG 1 S30 Chip Module, reels	9352 600 61118
HT1 MOA3 S30/E/1	HITAG 1 S30 Chip Module, bulk	9352 602 18122

Definitions

Data sheet status	
Objective specification	n This data sheet conta ins ta rget or goal specifications for product deve lopmer
Preliminary specification	n This data sheet conta ins preliminary data; supp lementary data may be published later.
Product spec ification	This data sheet conta ins final product spec ifications.
Limiting values	
Stress above one or m These are stress rating above those g iven in t	are in acco rdance with the Abso lute Maximum Rating Syste m (IEC 134). hore of the limiting values may cause pe rmanent da mage to the device. gs on ly and ope ration of the device at these or at any othe r conditions he Characteristics sect ion of the spec ification is not implied. Exposu re to ended pe riods may affect device ritigab
Application information	on
Where application info	ormation is given, it is advisory and does not form part of the spec ification

Life support applications

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors' customers using or selling these products for use in such applications do so on their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such improper use or sale.

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